Data Sheet



V 1.2 / Dec. 2018

MSM261D4030H1CPM

PDM digital output MEMS microphone with Multi-modes













GENERAL DESCRIPTION

MSM261D4030H1CPM is an omnidirectional, Top-ported, PDM digital output MEMS microphone. It has high performance and reliability.

MSM261D4030H1CPM is available in a thin 4 mm \times 3 mm \times 1 mm proprietary OCLGA package. It is SMT compatible with no sensitivity degradation.

APPLICATIONS

- ♦ Mobile Phone
- ♦ Laptop
- ♦ Tablet computer
- ♦ Bluetooth headset
- ♦ Earphone
- ♦ Wearable intelligent equipment

FEATURES

- ♦ High SNR
- → Fourth-order Σ-Δ modulator
- ♦ Digital PDM output
- Compatible with Sn/Pb and Pb-free solder processes
- ♦ RoHS/Halogen free compliant
- Multiple performance modes (Sleep, Low-Power, Standard Performance)
- ♦ Sensitivity Matching within +/-1dB

PRODUCT VIEW







ABSOLUTE MAXIMUM RATINGS

Parameter	Maximum value	Unit
Supply Voltage	-0.3 to 4.0	V
Sound Pressure Level	140	dB SPL
Storage temperature	-40 to 100	°C

ACOUSTIC & ELECTRICAL SPECIFICATIONS

TEST CONDITIONS: 23 ± 2 °C, 55 $\pm 20\%$ R.H., VDD=1.8 V, f_{CLOCK}=2.4 MHz, L/R pin grounded, no load, unless otherwise indicate

General Microphone Specifications

	Parameter	Symbol	Conditions	Min	Тур	Max	Units
Supply Voltage		V _{DD}		1.6	-	3.6	V
Clasti	Sleep Mode			0		50	KHz
Clock Frequency	Low-Power Mode			150		900	KHz
Range	Standard Performance Mode			1.1		4.0	MHz
	Sleep Current	ISLEEP	f _{CLOCK} ≤ 50 kHz	-	1		μΑ
	DC Output		Fullscale = ±100	-	4	-	% FS
	Directivity			Omnidirectional		al	
Polarity			Increasing sound	increasing density of 1's			of 1's
	Data Format			½ Cycle PDM			
Short Circuit Current		Isc	Grounded DATA pin	1	-	10	mA
	Output Load	CLOAD		-	-	200	рF
Fall-asleep Time			f _{CLOCK} ≤ 50 kHz	-	-	30	μs
Wake-up Time			f _{CLOCK} ≥ 151 kHz	-	-	200	μs
Power-up Time			V _{DD} ≥ V(min)	-	6	20	ms
N	lode-Change Time			-	-	10	ms











Standard Performance Mode

TEST CONDITIONS: f_{CLOCK} = 2.4 MHz, V_{DD}=1.8 V, unless otherwise indicated

Parameter	Symbol	Conditions		Тур	Max	Units
Supply Current	ldd	f _{CLOCK} =2.4 MHz		670	-	μА
Sensitivity	S	94 Db SPL @ 1 kHz		-26	-25	dBFS
Signal to Noise Ratio	SNR	20 kHz bandwidth, A-weighted f _{CLOCK} =2.4 MHz		64	-	dB(A)
Total Harmonic Distortion	THD	94 Db SPL @ 1 kHz, S = Typ		0.1	-	%
Acoustic Overload Point	AOP	10% THD @ 1 kHz, S = Typ		120	-	dB SPL
Power Supply Rejection Ratio	PSRR	200 mVpp sinewave @ 1 kHz		50	-	dBV/FS
Power Supply Rejection	PSR+N	100 mVpp square wave @ 217 Hz, A-weighted	-	-80	-	dBFS (A)











Low-Power Mode

TEST CONDITIONS: f_{CLOCK} =768 kHz, V_{DD} =1.8 V, unless otherwise indicated

Parameter	Symbol	Conditions		Тур	Max	Units
Supply Current	IDD	f _{CLOCK} =768KHz		290	-	μΑ
Sensitivity	S	94 Db SPL @ 1 kHz		-25	-24	dBFS
Signal to Noise Ratio	SNR	94 Db SPL @ 1 kHz, A-weighted(20Hz-8KHz)	-	62	-	dB(A)
Total Harmonic Distortion	THD	94 Db SPL @ 1 kHz, S = Typ	-	0.1	-	%
Acoustic Overload Point	АОР	10% THD @ 1 kHz, S = Typ	-	120	-	dB SPL
Power Supply Rejection Ratio	PSRR	200 mVpp sinewave @ 1 kHz	-	50	-	dBV/FS
Power Supply Rejection	PSR+N	100 mVpp square wave @ 217 Hz, A-weighted(20Hz-8KHz)	-	-80	-	dBFS (A)

Microphone Interface Specifications

<u> </u>						
Parameter	Symbol	Conditions	Min	Тур	Max	Units
Logic Input High	Vih		0.7Xv _{DD}	-	3.6	V
Logic Input Low	VıL		-0.3	-	0.3Xv _{DD}	V
Logic Output High	Vон	I _{OUT} = 2 Ma	V _{DD} -0.45	-	-	V
Logic Output Low	Vol	I _{OUT} = 2 Ma	-	-	0.45	V
Clock Duty Cycle		-	40	-	60	%



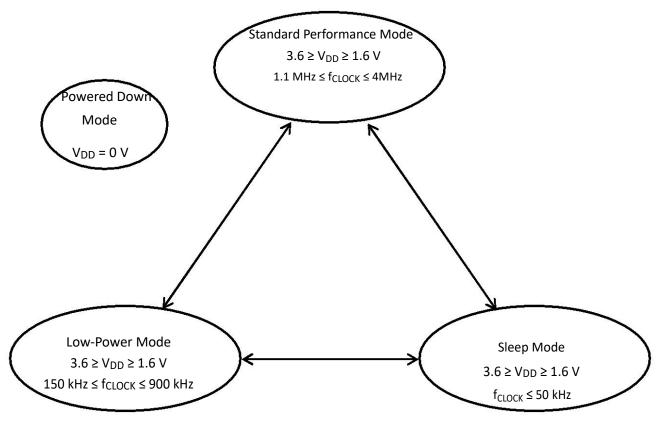








MICROPHONE STATE DIAGRAM







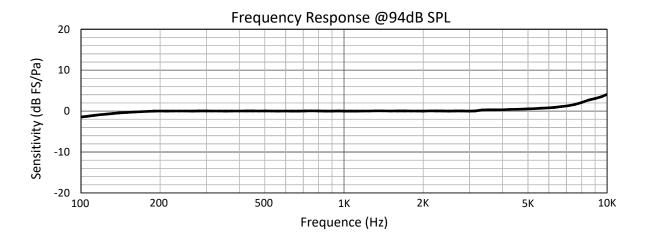




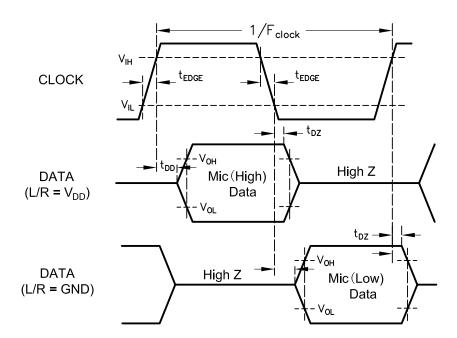




TYPICAL FREQUENCY RESPONSE



TIMING DIAGRAM



Parameter	Symbol	Min	Тур	Max
Clock Rise/Fall Time	t _{EDGE}	-	-	20ns
Delay Time to High Z	t _{DZ}	-	-	40ns
Delay Time to Data Line Driven	t _{DD}	-	•	50ns

Microphone	L/R	Asserts DATA on	Latch DATA on
Mic(High)	Vdd	CLK rising edge	CLK falling edge
Mic(Low)	Ground	CLK falling edge	CLK rising edge





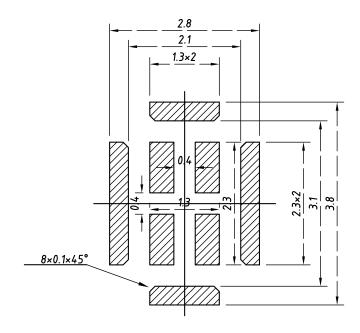






SMT Parameters:

1. Recommend PCB land pattern layout: (unit: mm)





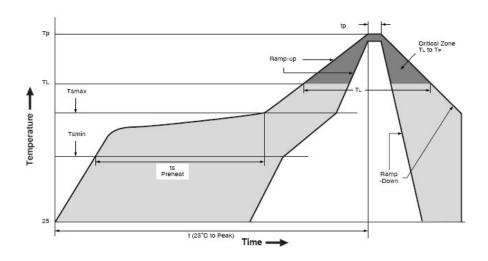








2. Recommend reflow profile:



Description	Parameter	Pb-free
Average ramp rate	T _L to T _P	3 °C/sec max
Preheat		
Minimum temperature	T _{SMIN}	150 °C
Maximum temperature	T _{SMAX}	200 °C
Time(T _{SMIN} to T _{SMAX})	ts	60 sec to 120 sec
Ramp-up rate	T _{SMAX} to T _L	1.25 °C/sec max
Time maintained above liquidus temperature	t _L	60 sec to 150 sec
Liquidus temperature	TL	217 °C
Peak temperature	T _P	260 °C max
Time within 5°C of actual peak temperature	t _P	20 sec to 40 sec
Ramp-down rate	T _L to T _P	6 °C/sec max
Time 25 °C (t25 °C) to peak temperature	t	8 minutes max



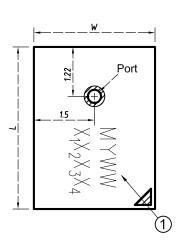


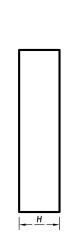


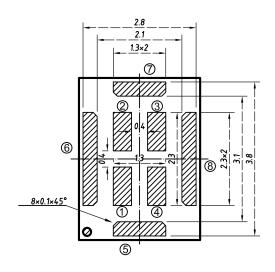


OUTLINE DIMENSIONS AND PIN DEFINITION:









TOP VIEW

SIDE VIEW

BOTTOM VIEW

PIN function description

	•
PIN#	Function
1	VDD
2	L/R
3	CLK
4	DATA
5,6,7,8	GND

Item	Dimension	Tolerance
Length (L)	4.00	±0.10
Width (W)	3.00	±0.10
Height (H)	1.00	±0.10
Port (AP)	Ø0.325	±0.05

Dimensions are in millimeters, tolerance is ±0.15mm unless otherwise specified.

	М	Memsensing
MYWW	Υ	Year(A~Z)
$X_1X_2X_3X_4$	ww	Week
	$X_1X_2X_3X_4$	Serial Number











ADDITIONAL NOTES

- (A) MSL (moisture sensitivity level) Class 1.
- (B) Maximum of 3 reflow cycles is recommended.

I In order to minimize device damage:

Do not board wash or clean after the reflow process.

Do not brush board with or without solvents after the reflow process.

Do not directly expose to ultrasonic processing, welding, or cleaning.

Do not insert any object in port hole of device at any time.

Do not apply air pressure into the port hole.

Do not pull a vacuum over port hole of the microphone.

STORAGE AND TRANSPORTATION

- (A) Keep MEMS MIC in warehouse with less than 75% humidity and without sudden temperature change, acid air, any other harmful air or strong magnetic field.

 Recommend floor life (out of bag) at factory no more than 4 weeks.
- (B) The MEMS MIC with normal pack can be transported by ordinary conveyances. Please protect products against moist, shock, sunburn and pressure during transportation.

MATERIALS STATEMENT

Meet the requirements of MEMSensing standard on hazard substances control (including RoHS2.0+REACH+Halogen-Free, etc.), with "HSF" identification on label.

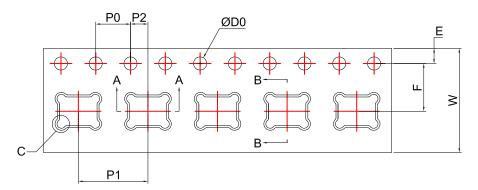


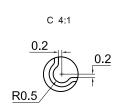


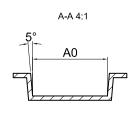


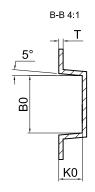


PACKAGING & MARKING DETAIL:

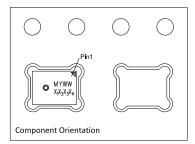








Direction of Feed



ITEM	W	Ш	F	ØD0	K0
DIM(mm)	12.00±0.30	1.75±0.10	5.50±0.10	1.500+0.10	1.35±0.10
ITEM	P0	10P0	P1	A0	В0
DIM(mm)	4.00±0.10	40.00±0.20	8.00±0.10	4.30±0.10	3.30±0.10
ITEM	P2	Т			
DIM(mm)	2.00±0.10	0.25±0.05			

Note:

- 1) Dimensions are in mm;
- 2) Don't put the vacuum suction nozzle alignment the port hole;
- 3) Tape & Reel Per EIA-481 standard;
- 4) Label applied to external package and direct to reel;
- 5) Static voltage <100V;

Model Number	Reel Diameter	Quantity Per Reel	
MSM261D4030H1CPM	13 inch	5700	



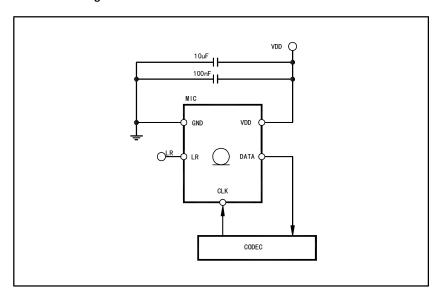




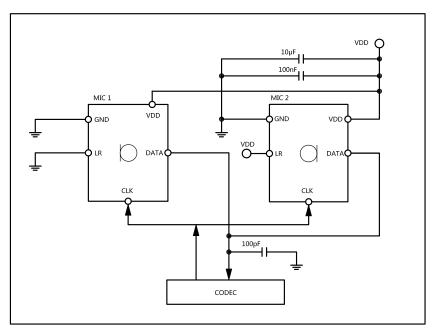


RECOMMENDED INTERFACE CIRCUIT:

Figuer 1. MSM261D4030H1CPM electrical connections



Figuer 2. Electrical connections for stereo configurations



Power supply decoupling capacitors (100Nf ceramic,10Uf ceramic) should be placed as near as possible to VDD of the device.(common design practice)











RELIABILITY SPECIFICATIONS

Test	Description	
Thermal Shock	100 cycles air-to-air thermal shock from -40°C to +125°C with 15 minute soaks.	
High Temperature Storage	1,000 hours at +105°C environment	
Low Temperature Storage	1,000 hours at -40°C environment	
Reflow	5 reflow cycles with peak temperature of +260°C	
ESD-HBM	3 discharges of ±2 Kv direct contact to I/O pins.	
ESD- LID-GND	3 discharges of ±8 Kv direct contact to lid while unit is grounded.	
ESD-MM	3 discharges of±200V direct contact to I/O pins.	
Vibration	4 cycles of 20 to 2,000 Hz sinusoidal sweep with 20 G peak acceleration lasting 12 minutes in X, Y and Z directions.	
Mechanical Shock	3 pulses of 10,000 G in the X, Y and Z direction	
High Temperature Bias	1,000 hours at +105°C under bias	
Low Temperature Bias	1,000 hours at -40°C under bias	
Temperature/Humidity Bias	1,000 hours at +85°C/85% R.H. under bias.	
Drop Test	To be no interference in operation after dropped to 1.0cm steel plate 18 times from 1.5 meter height	

NOTE: Sensitivity should vary within $\pm 3Db$ from initial sensitivity. (The measurement to be done after 2 hours of conditioning at 20 ± 2 °C,R.H 60%~70%)

MSM261D4030H1CPM

PDM digital output MEMS microphone









REVISION HISTORY:

Revision	Subjects (major changes since last revision)	Date
1.0	Initial Release	2018-06-20
1.1	Update typical of SNR	2018-09-17
1.2	Update typical of THD	2018-12-29

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